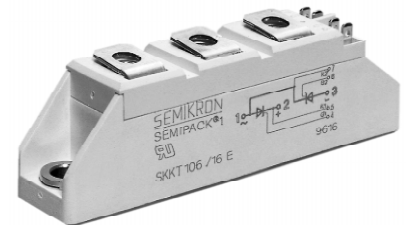


V <sub>RSM</sub>	V <sub>RRM</sub>	(dv/dt) <sub>cr</sub>	I <sub>TRMS</sub> (maximum value for continuous operation)			
	V <sub>DRM</sub>		150 A			
V	V	V/μs	I <sub>TAV</sub> (sin. 180; T <sub>case</sub> = 85°C)			
			95 A			
500	400	500	–	–	SKKH 91/04 D	–
700	600	500	SKKT 91/06 D	SKKT 92/06 D	SKKH 91/06 D	SKKH 92/06 D
900	800	500	SKKT 91/08 D	SKKT 92/08 D	SKKH 91/08 D	SKKH 92/08 D
1300	1200	1000	SKKT 91/12 E	SKKT 92/12 E <sup>1)</sup>	SKKH 91/12 E	SKKH 92/12 E
1500	1400	1000	SKKT 91/14 E	SKKT 92/14 E <sup>1)</sup>	SKKH 91/14 E	SKKH 92/14 E
1700	1600	1000	SKKT 91/16 E	SKKT 92/16 E <sup>1)</sup>	SKKH 91/16 E	SKKH 92/16 E
1900	1800	1000	SKKT 91/18 E	SKKT 92/18 E <sup>1)</sup>	SKKH 91/18 E	SKKH 92/18 E

## SEMIKRON® 1 Thyristor / Diode Modules

SKKT 91      SKKH 91  
SKKT 92      SKKH 92  
SKKT 92B     SKMT 92<sup>2)</sup>  
SKKL 92<sup>2)</sup>



Symbol	Conditions	SKKT 91 SKKH 91	SKKT 92 SKKT 92B SKKH 92	Units
I <sub>TAV</sub>	sin. 180; T <sub>case</sub> = 85°C	95		A
I <sub>D</sub>	B2/B6 T <sub>amb</sub> = 45 °C; P 3/180	70 / 85		A
	T <sub>amb</sub> = 35 °C; P 3/180 F	140/ 175		A
I <sub>RMS</sub>	W1/W3 T <sub>amb</sub> = 35 °C; P 3/180 F	190 / 3 x 135		A
I <sub>TSM</sub>	T <sub>vj</sub> = 25 °C; 10 ms	2 000		A
	T <sub>vj</sub> = 125 °C; 10 ms	1 750		A
i <sup>2</sup> t	T <sub>vj</sub> = 25 °C; 8,3 ... 10 ms	20 000		A <sup>2</sup> s
	T <sub>vj</sub> = 125 °C; 8,3 ... 10 ms	15 000		A <sup>2</sup> s
t <sub>gd</sub>	T <sub>vj</sub> = 25 °C; I <sub>G</sub> = 1 A; di <sub>G</sub> /dt = 1 A/μs	1		μs
t <sub>gr</sub>	V <sub>D</sub> = 0,67 · V <sub>DRM</sub>	2		μs
(di/dt) <sub>cr</sub>	T <sub>vj</sub> = 125 °C	150		A/μs
t <sub>q</sub>	T <sub>vj</sub> = 125 °C	typ. 100		μs
I <sub>H</sub>	T <sub>vj</sub> = 25 °C; max.	250		mA
I <sub>L</sub>	T <sub>vj</sub> = 25 °C; R <sub>G</sub> = 33 Ω; max.	600		mA
V <sub>T</sub>	T <sub>vj</sub> = 25 °C; I <sub>T</sub> = 300 A	max. 1,65		V
V <sub>T(TO)</sub>	T <sub>vj</sub> = 125 °C	0,9		V
r <sub>T</sub>	T <sub>vj</sub> = 125 °C	2		mΩ
I <sub>DD</sub> ; I <sub>RD</sub>	T <sub>vj</sub> = 125 °C; V <sub>RD</sub> = V <sub>RRM</sub> V <sub>DD</sub> = V <sub>DRM</sub>	max. 20		mA
V <sub>GT</sub>	T <sub>vj</sub> = 25 °C; d.c.	3		V
I <sub>GT</sub>	T <sub>vj</sub> = 25 °C; d.c.	150		mA
V <sub>GD</sub>	T <sub>vj</sub> = 125 °C; d.c.	0,25		V
I <sub>GD</sub>	T <sub>vj</sub> = 125 °C; d.c.	6		mA
R <sub>thjc</sub>	cont. } per thyristor /	0,28 / 0,14		°C/W
	sin. 180 } per module	0,30 / 0,15		°C/W
	rec. 120 } per module	0,32 / 0,16		°C/W
R <sub>thch</sub>		0,2 / 0,1		°C/W
T <sub>vj</sub>		– 40 ... + 125		°C
T <sub>stg</sub>		– 40 ... + 125		°C
V <sub>isol</sub>	a. c. 50 Hz; r.m.s.; 1 s/1 min	3600 / 3000		V~
M <sub>1</sub>	to heatsink } SI (US) units	5 (44 lb. in.) ± 15 % <sup>3)</sup>		Nm
M <sub>2</sub>	to terminals }	3 (26 lb. in.) ± 15 %		Nm
a		5 · 9,81		m/s <sup>2</sup>
w	approx.	95		g
Case	→ page B 1 – 95	SKKT 91: A 5	SKKL 92: A 59	
		SKKH 91: A 6	SKKT 92: A 46	
		SKMT 92: A 72	SKKH 92: A 47	
			SKKT 92B: A 48	



SKKT 91      SKKH 91



SKKT 92  
SKKT 92B      SKKH 92



SKMT 92      SKKL 92

### Features

- Heat transfer through aluminium oxide ceramic isolated metal baseplate
- Hard soldered joints for high reliability
- UL recognized, file no. E 63 532

### Typical Applications

- DC motor control (e.g. for machine tools)
- AC motor soft starters
- Temperature control (e.g. for ovens, chemical processes)
- Professional light dimming (studios, theaters)

1) Also available in SKKT 92B configuration (case A 48)

2) SKKL 92, SKMT 92 available on request

3) See the assembly instructions

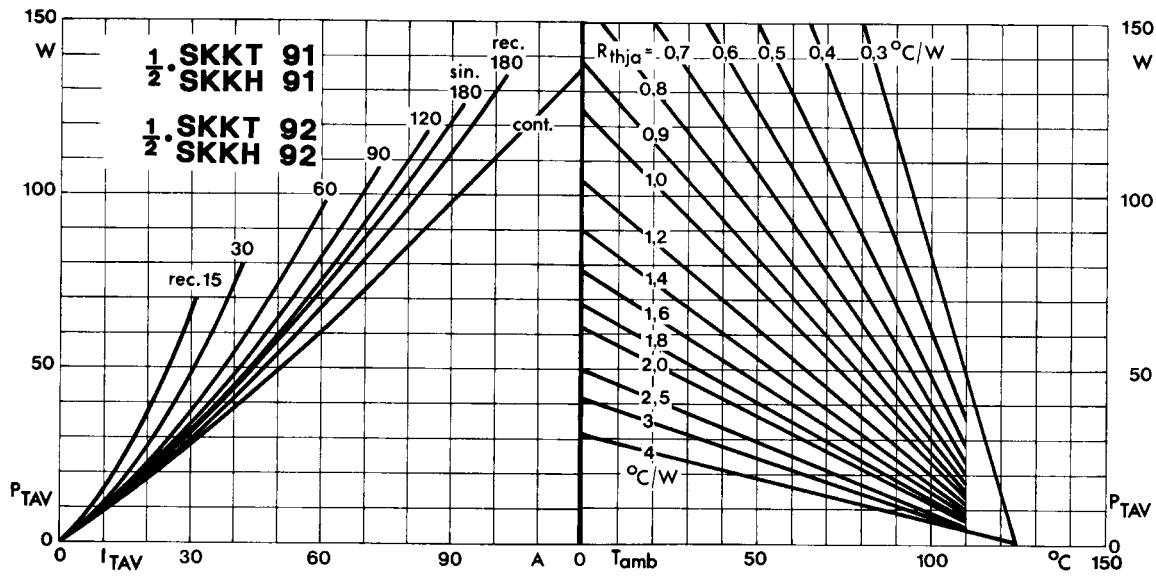


Fig. 1 Power dissipation per thyristor vs. on-state current and ambient temperature

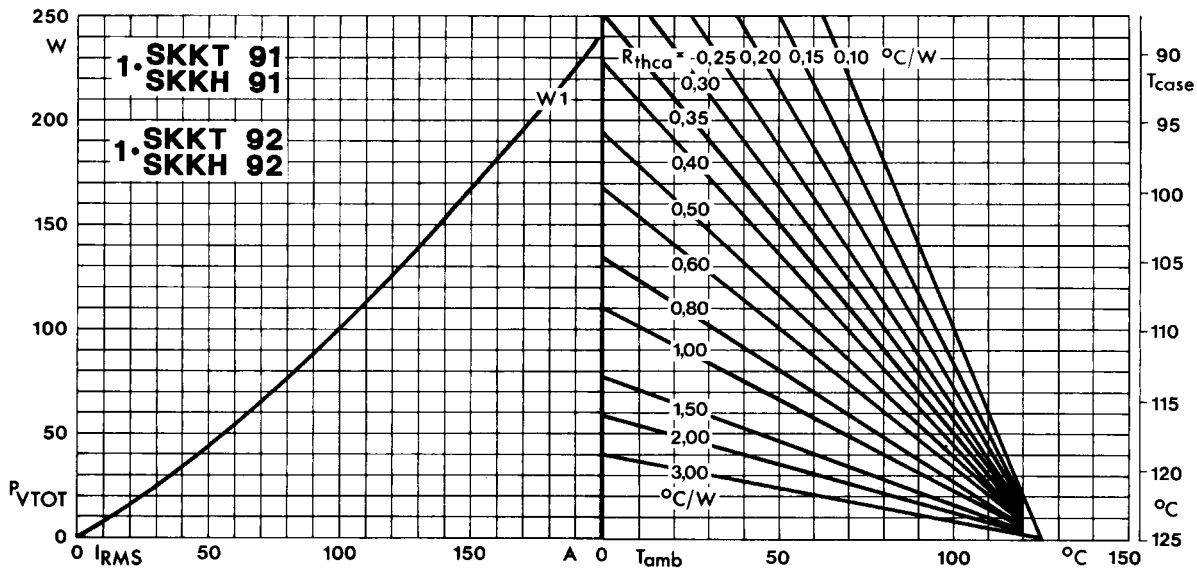


Fig. 2 Power dissipation per module vs. rms current and case temperature

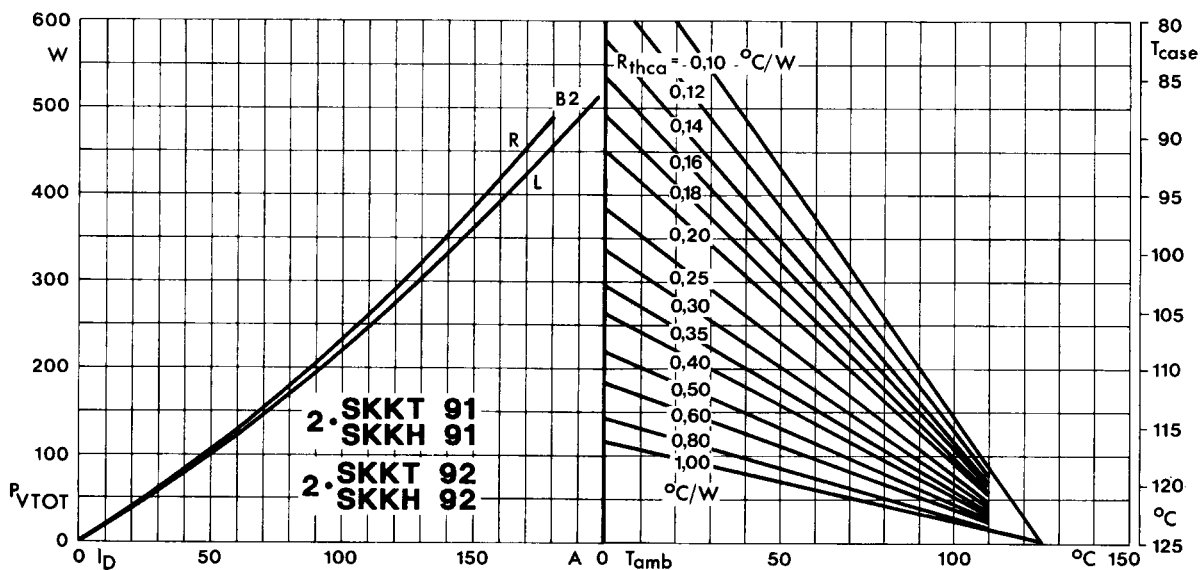


Fig. 3 Power dissipation of two modules vs. direct current and case temperature

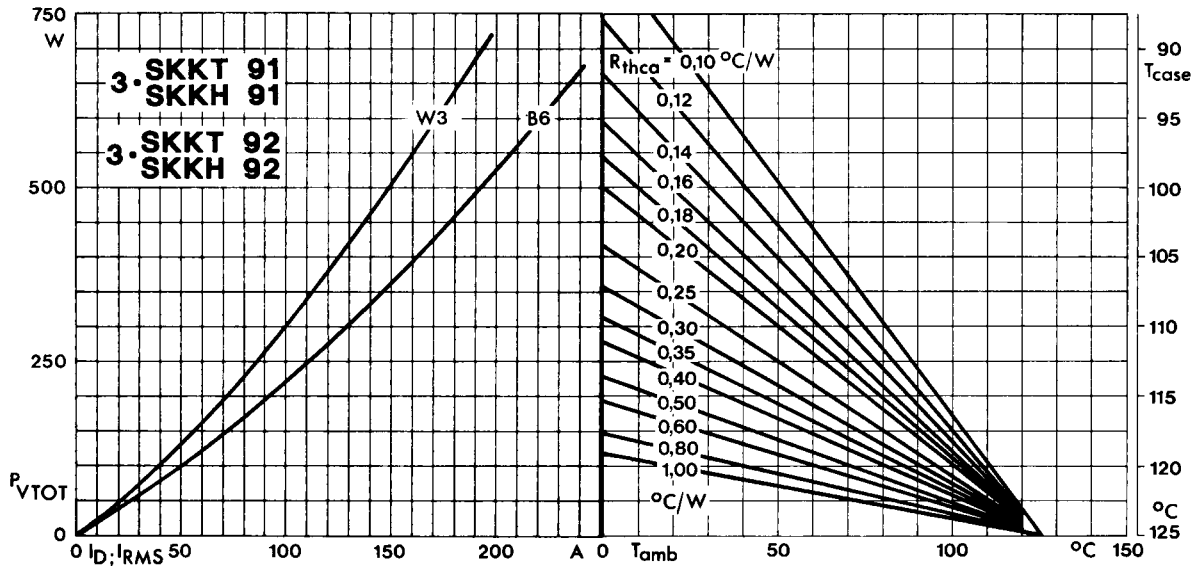


Fig. 4 Power dissipation of three modules vs. direct and rms current and case temperature

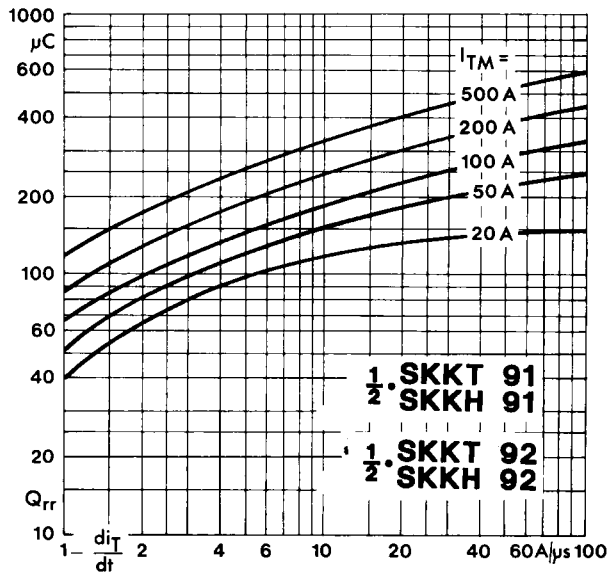


Fig. 5 Recovered charge vs. current decrease

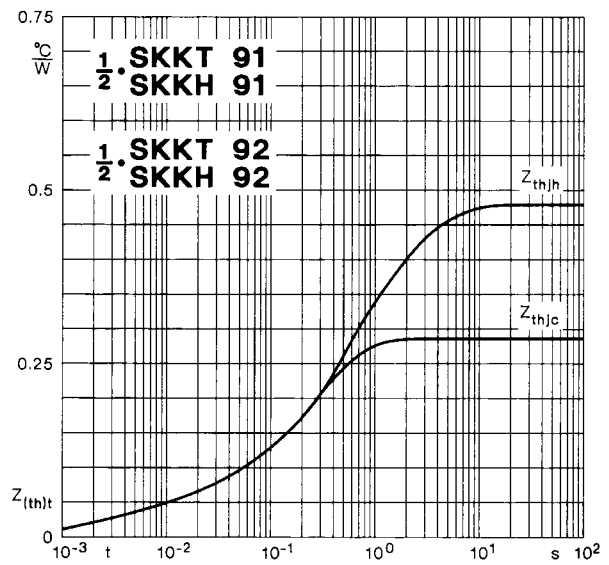


Fig. 6 Transient thermal impedance vs. time

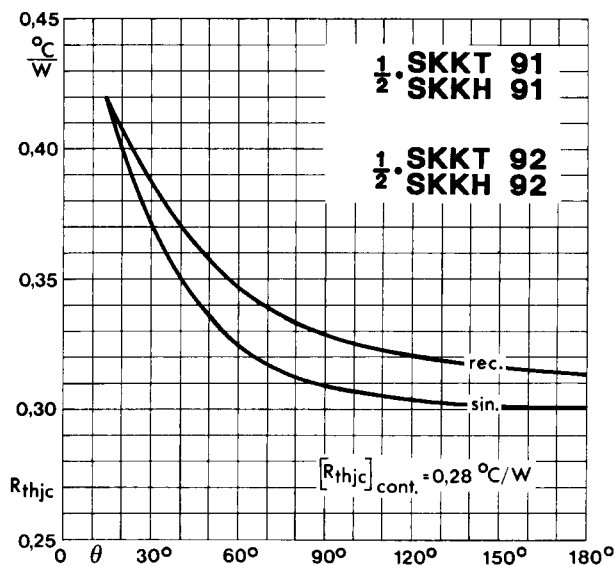


Fig. 7 Thermal resistance vs. conduction angle

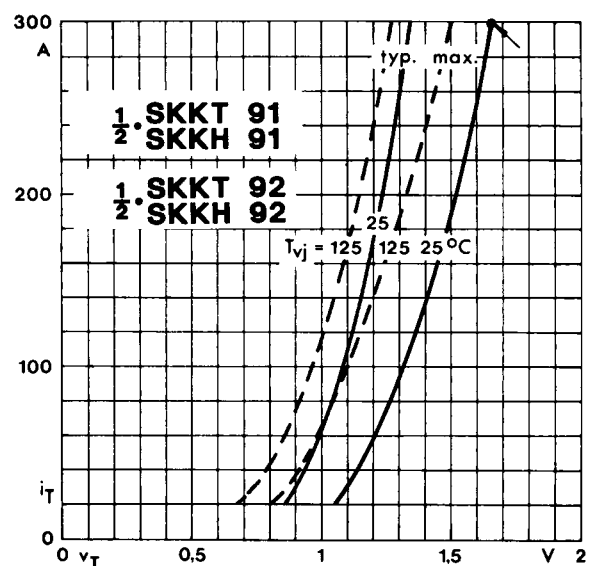


Fig. 8 On-state characteristics

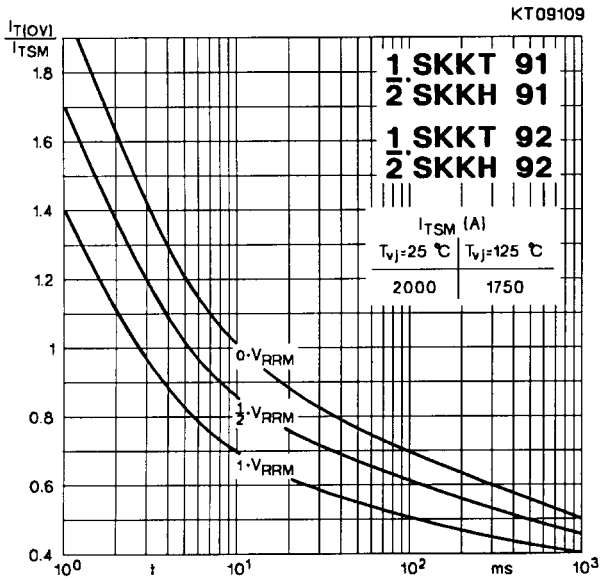


Fig. 9 Surge overload current vs. time

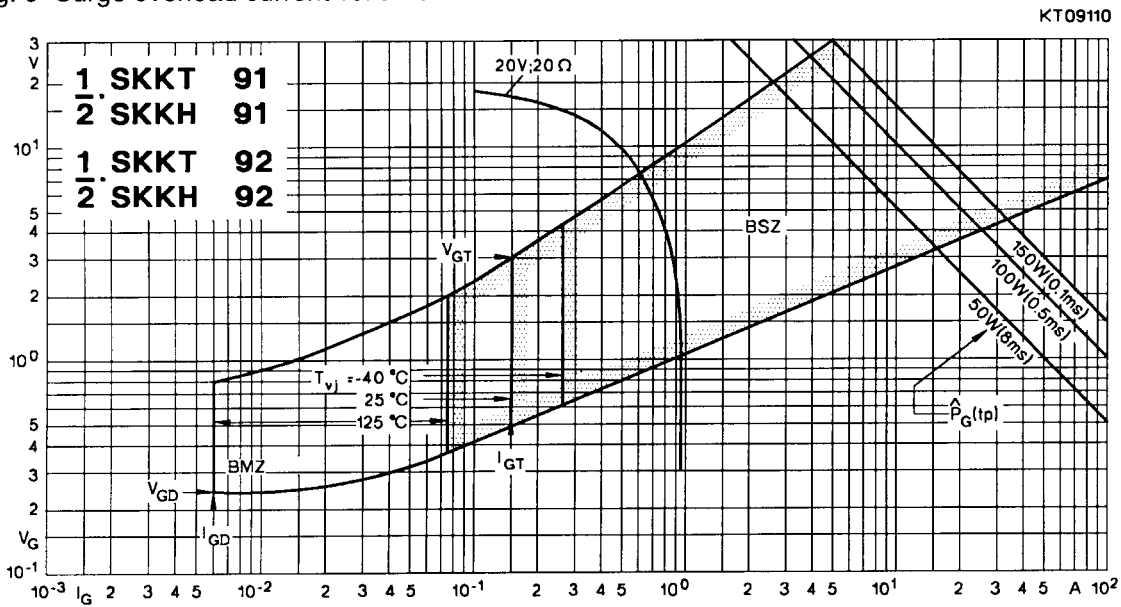


Fig. 10 Gate trigger characteristics

## SKKT 19 ... 105

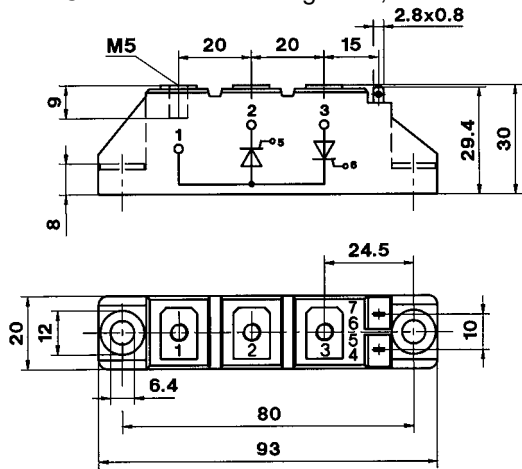
Case A 5

IEC 192-2: A 77 A

JEDEC: TO-240 AA

SEMIPACK® 1

UL recognized, file no. E 63 532



Dimensions in mm

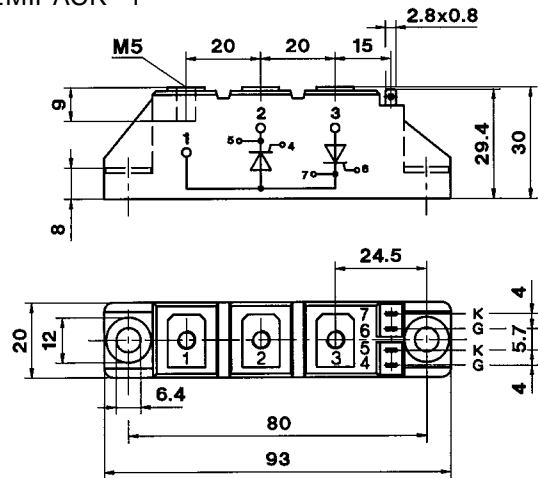
## SKKT 20/ ... 106/

Case A 46

IEC 192-2: A 77 A

JEDEC: TO-240 AA

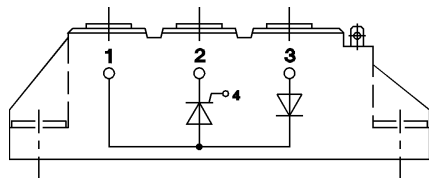
SEMIPACK® 1



Dimensions in mm

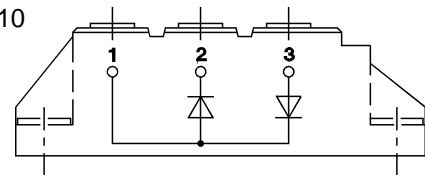
## SKKH 26 ... 105

Case A 6



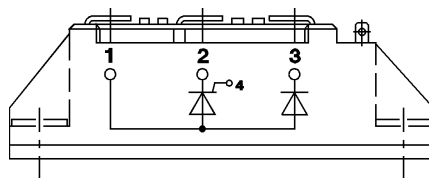
## SKKD 26 ... 100

Case A 10



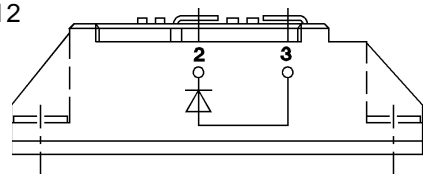
## SKNH 56 ... 91

Case A 7



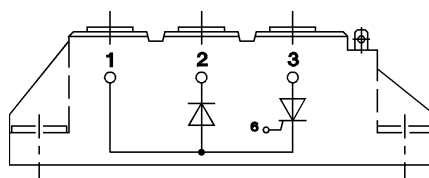
## SKKE 81

Case A 12



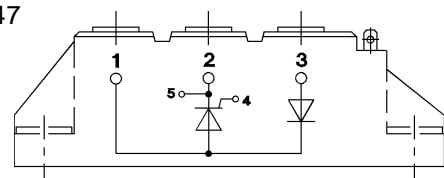
## SKKL 56 ... 105

Case A 9



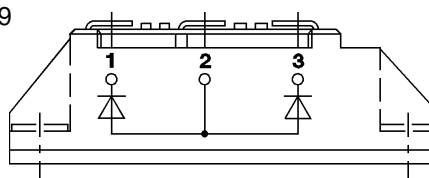
## SKKH 27 ... 106

Case A 47



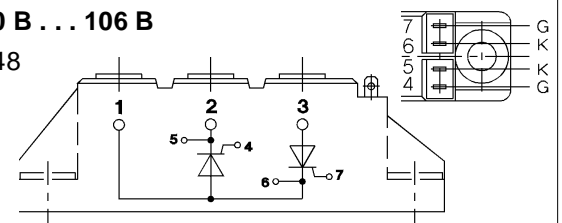
## SKND 46 ... 81

Case A 19



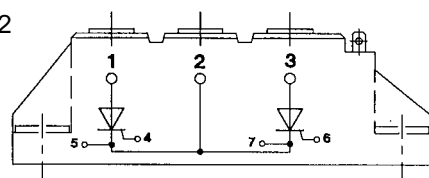
## SKKT 20 B ... 106 B

Case A 48



## SKMT 92

Case A 72



## SKKL 42 ... 106

Case A 59

